

INTERNATIONAL RECTIFIER



1N3208 SERIES

15 Amp Stud-mounted Silicon Rectifier Diodes

Major Ratings and Characteristics

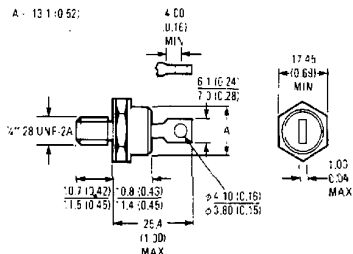
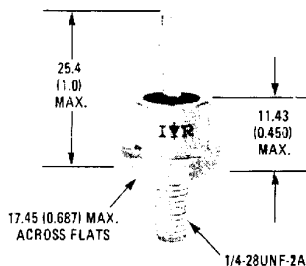
	1N3208	Units
$I_F(AV)$	15*	A
T_C	150*	$^{\circ}C$
I_{FSM} @ 50 Hz	239	A
@ 60 Hz	250*	
I_{2T} @ 50 Hz	286	A 2s
@ 60 Hz	260	
$I_2 \sqrt{t}$	3870	A $^2 \sqrt{s}$
V_{RRM} Range	50-600	V

* JEDEC registered values.

Description/Features

- Low thermal impedance
- High case temperature
- Excellent reliability
- Maximum design flexibility
- Can be made to meet stringent military, aerospace and other high-reliability requirements.

CASE STYLE AND DIMENSIONS



Conforms TO JEDEC Outline DO-203AB (DO-5)

All Dimensions in Millimeters and Inches

VOLTAGE RATINGS

Part Number		V _{RRM} - Max. Repetitive Peak Reverse Voltage (V)	V _R - Max. Direct Reverse Voltage (V)
cathode-to-case	anode-to-case	T _J = -65°C to 175°C	T _J = -65°C to 175°C
1N3208	1N3208R	50*	50*
1N3209	1N3209R	100*	100*
1N3210	1N3210R	200*	200*
1N3211	1N3211R	300*	300*
1N3212	1N3212R	400*	400*
1N3213	1N3213R	500*	500*
1N3214	1N3214R	600*	600*

ELECTRICAL SPECIFICATIONS

		Units	Conditions
I _{F(AV)} Max. average forward current	15*	A	180° sinusoidal conduction, max. T _C = 150°C*
I _{FSM} Max. peak one-cycle non-repetitive surge current	239	A	Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with rated V _{RRM} applied
	250*		Half cycle 60 Hz sine wave or 5 ms rectangular pulse
	284		Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with V _{RRM} applied following surge = 0.
	297		Half cycle 60 Hz sine wave or 5 ms rectangular pulse
I _{2t} Max. I _{2t} for fusing	286	A ² s	t = 10 ms With rated V _{RRM} applied following surge, initial
	260		t = 8.3 ms T _J = 150°C.
	403		t = 10 ms With V _{RRM} = 0 following surge, initial T _J = 150°C
	368		t = 8.3 ms
I ₂ √t Max. I ₂ √t for individual device fusing ①	3870	A ² √s	t = 0.1 to 10 ms, V _{RRM} = 0 following surge.
V _{FM} Max. peak forward voltage	1.5*	V	I _{F(AV)} = 15A (47.1A peak), T _C = 150°C.
I _{R(AV)} Max. average reverse current	10*	mA	Max. rated I _{F(AV)} and T _C = 150°C

THERMAL MECHANICAL SPECIFICATIONS

T _J Max. operating junction temperature range	-65 to 175*	°C	
T _{stg} Max. storage temperature range	-65 to 175*	°C	
R _{thJC} Max. internal thermal resistance, junction-to-case	0.65	deg C/W	DC operation
R _{thCS} Thermal resistance, case-to-sink	0.25	deg C/W	Mounting surface flat, smooth, and greased
T Mounting torque	Min. 2.3 (20) Max. 3.5 (30)	N·m (lbf-in)	Non-lubricated threads
wt Approximate weight	28.5 (1)	g (oz)	
Case style	DO-203AB(DO-5)	JEDEC	

* JEDEC registered values.

① I_{2t} for time t_x = I₂√t · √t_x.

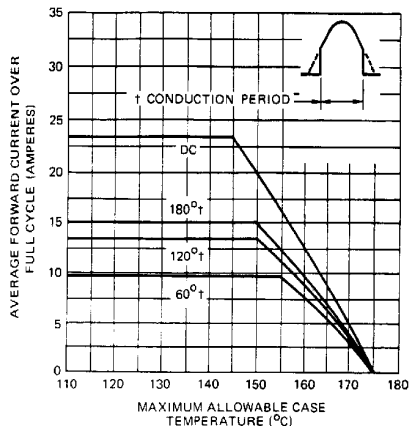


Fig. 1 - Average Forward Current Vs. Maximum Allowable Case Temperature

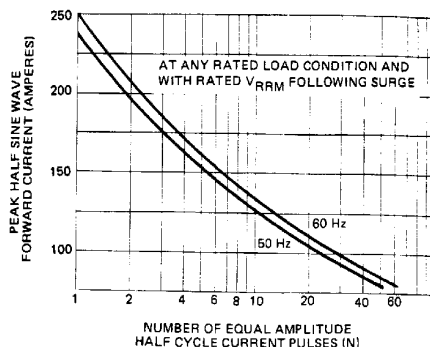


Fig. 2 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses

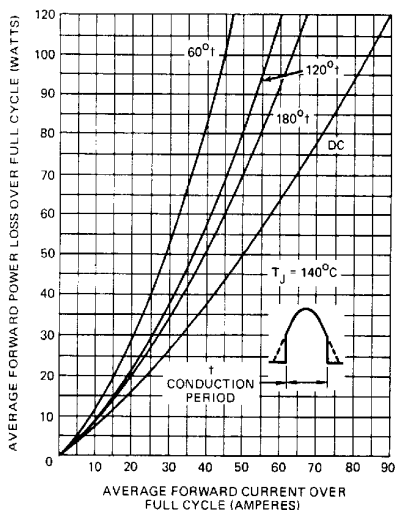


Fig. 3 - Maximum Low Level Forward Power Loss Vs. Average Forward Current

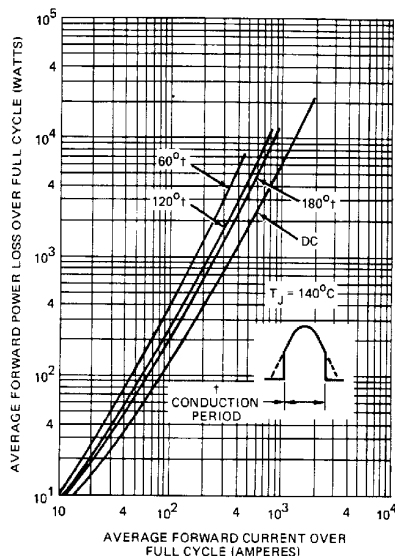


Fig. 4 - Maximum High Level Forward Power Loss Vs. Average Forward Current

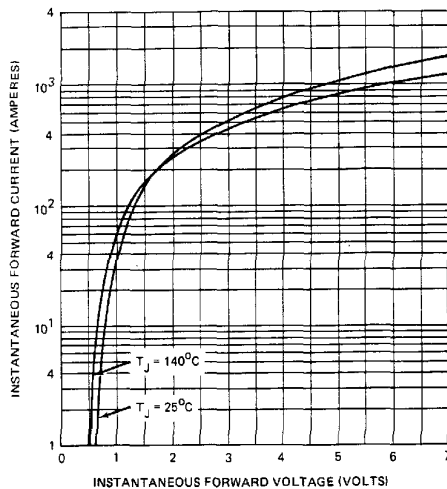


Fig. 5 — Maximum Forward Voltage
Vs. Forward Current